TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

## TA8132AN,TA8132AF,TA2012N,TA2012F

3V AM / FM IF + MPX (For Digital Tuning System)

TA8132AN, TA8132AF and TA2012N, TA2012F are the AM / FM IF+ST DET system ICs, which are designed for DTS radios. These are included many functions and these can be used for digital tuning system with IF counter.

#### **Features**

- Built-in AM / FM IF and FM stereo PLL multiplex decoder.
- Suitable for combination with digital tuning system which is included IF counter.
  - One terminal type AM / FM IF count output (auto stop signal) for IF counter of digital tuning system.

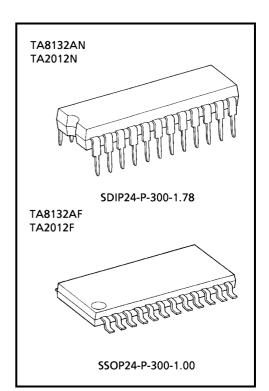
FM: 10.7MHz or 1.3375MHz (1 / 8 dividing) changeable by external switch

AM: 450kHz

Built-in mute circuit for IF count output.
 It is controlled by the IF request signal from digital tuning system,

Pin(8) level: High  $\rightarrow$  come out Low  $\rightarrow$  non output

- O Adjustable for IF count output sensitivity by external resistance of pin(2).
- For adopting ceramic discriminator and ceramic resonator, it is not necessary to adjust the FM quad detector circuit and FM ST DET VCO circuit.



Weight

SDIP24-P-300-1.78: 1.2g (typ.) SSOP24-P-300-1.00: 0.31g (typ.)

• S curve characteristics of FM detection output in TA8132AN, TA8132AF and TA2012N, TA2012F are reverse to each other.

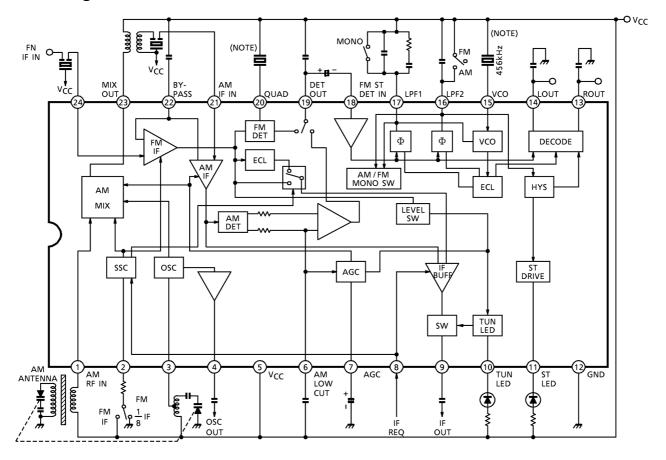
TA8132AN, TA8132AF: Reverse characteristic.

TA2012N, TA2012F: Normal characteristic.

- Built-in one terminal type AM low cut circuit.
- TA2053F is reverse pin type of TA2012F.
- Operating supply voltage range (Ta = 25°C)

 $V_{CC (opr.)} = 1.8 \sim 8.0 V$ 

### **Block Diagram**



(Note)

We recommend

Ceramic resonator: CSB456F18

Ceramic discriminator: CDA10.7MG18 (MURATA MFG CO., LTD)



# **Explanation Of Terminals**

Pin	Item	Internal Circuit	DC Vol	tage (V) Signal)
No.			AM	FM
1	AM RF IN	VCC (S)	3.0	3.0
2	IF count output sensitivity adjust terminal     FM IF divider control terminal	VCC 5  GND 12  2	_	_
3	AM OSC	VCC S BUFF AMP ALC	3.0	3.0
4	AM OSC OUT	V <sub>CC</sub> (S) AM OSC AM OSC AM OSC AM OSC	2.7	3.0
5	Vcc	_	3.0	3.0
6	AM LOW CUT	V <sub>CC</sub> (5)	2.3	2.3

Pin	Item	Internal Circuit	DC Vol	tage (V) Signal)
No.			AM	FM
7	AGC	VCC S  GND (2)  SEARCH MODE : HIGH	0.25	0.35
8	IF OUT SW	8——————————————————————————————————————	Ι	_
9	IF OUT	GND (12)	3.0	3.0
10	TUN LED (tuning LED)	V <sub>CC</sub> (5) (10) (10) (10) (10) (10) (10) (10) (10	_	_
11	ST LED (stereo LED)	19kHz 11) GND (12)	Ι	_
12	GND	_	0	0
13 14	R-OUT L-OUT	V <sub>CC</sub> (5)	1.0	1.0

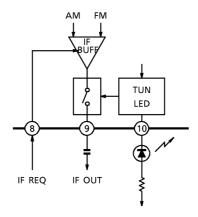
Pin	Item	Internal Circuit	DC Vol	tage (V) Signal)
No.	item	internal Circuit	AM	FM
15	VCO	V <sub>CC</sub> (5) (15) (15) (17) (17) (17) (17) (17) (17) (17) (17	2.5	2.5 (VCO stop mode)
16	LPF2  • LPF terminal for synchronous detector  • Bias terminal for AM / FM switch circuit  V <sub>16</sub> = V <sub>CC</sub> →AM  V <sub>16</sub> = open→FM	GND 12	3.0	2.2
17	LPF1  • LPF Terminal for phase detector  • VCO stop terminal  V <sub>17</sub> = V <sub>CC</sub> →VCO stop	GND 12	2.7	2.2
18	FM ST DET IN	(B) (12) (GND (12)	0.7	0.7
19	DET OUT	VCC S  AM  FM  GND 12	1.1	1.1

Pin	Item	Internal Circuit	DC Vol	tage (V) Signal)
No.			AM	FM
20	QUAD (FM QUAD. Detector)	V <sub>CC</sub> (5) (20) (10) (10) (10) (10) (10) (10) (10) (1	2.4	2.1
21	AM IF IN	Vcc (5) C2 (2) (2) (1) (1) (1) (1) (1) (1) (1) (1) (1) (1	3.0	3.0
22	BY-PASS By-pass for AM/FM IF AMP	GND (12)	2.3	2.8
23	AM MIX OUT	VCC (S)  MIX  GND (12)	3.0	3.0
24	FM IF IN	VCC (S)  BY-PASS (22)  GND (12)	3.0	3.0



### **Application Note**

1. How to control the IF count output signal (pin(9) output)



		TUN I	_ED
		ON	OFF
Va	Н	Come out	Non output
V <sub>8</sub>	L	Non output	Non output

• Whether or not there is the IF count output signal (pin(9) output) is determined by the and of the pin(8) control voltage: V<sub>8</sub> and tuning LED on / off switching.

In the condition of

V<sub>8</sub>: High (active high, V<sub>TH</sub> = 0.8V (typ.))

TUN LED: ON  $(V_{in} \ge V_L + 2dB\mu V EMF (typ.))$ 

the IF count output signal comes out from the pin(9).

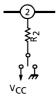
In the case of the tuning LED function is not needed, it doesn't matter the pin(10) is opened.

- The output impedance of pin(9) is 1.5kΩ (typ.) (cf.P.4)
   It is possible to reduce the IF count output signal level to add the resistance between the pin(9) and the VCC line
- The signal waveform is the rectangular wave, and the level is  $500 \text{mV}_{p-p}$  (typ.)
- 2. How to control the divider of FM IF

- 3. How to adjust the IF count output sensitivity
  - The IF count output sensitivity (search sensitivity)

    Can be adjusted by varying the IF AMP gain for FM and varying the MIXER gain for AM.

    This setting is made by changing the value of external resistance R<sub>2</sub> which is connected to pin(2).



• However, this is only possible at the auto-tuning mode. (external voltage supplied to pin(8) is at high level.) The original again returns while receiving a broadcast station (supplied voltage to pin(8) is at low level.)

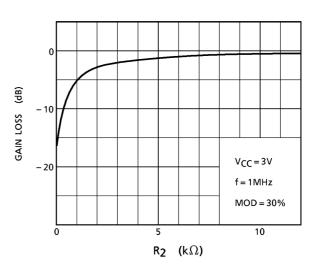
• The gain loss of FM IF AMP

		R	2
		0Ω	10KΩ (Note)
Mode	IF (10.7MHz)	-20dB	-1dB
Mo	1 / 8 IF (1.3375MHz)	-20dB	-1dB

(Note)

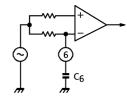
- In the condition of the 1 / 8 IF mode, it is possible to set up  $R_2 = \infty$  (OPEN).
- In the condition of IF mode, it is necessary to set up the value of  $R_2$  under  $10k\Omega$ . When the  $R_2$  is over  $10k\Omega$  it is feared that the mode is change to the 1 / 8 IF mode.
- The gain loss of AM MIXER

R <sub>2</sub>	2
Ω0	10ΚΩ
-16dB	-1dB



#### 4. AM low-cut circuit

 $\bullet$  The AM low–cut action is carried out by the bypass of the high frequency component of the positive–feedback signal at the AF AMP stage. The external capacitor: C6 by–passes this component.



• The cut–off frequency  $f_L$  is determine by the internal resistance  $22k\Omega$  (typ.) and the external capacitor  $C_6$  as following;

$$f_L = \frac{1}{2 \times \pi \times 22 \times 10^3 \times C_6} (Hz)$$

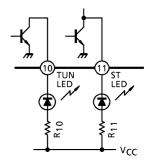
• In the case of the AM low–cut function is not needed, set up the value of  $C_6$  over  $0.47\mu F$ . In the condition of  $C_6 \ge 0.47\mu F$ , the frequency characteristic has flat response at the low frequency.

#### 5. AM local oscillator buffer output

- The output impedance of AM local oscillator buffer output pin (pin(4)) is  $750\Omega$  (typ.) (cf.P.3)
- It is possible to reduce the output level to add the resistance between the pin(4) and  $V_{CC}$  line. The signal waveform is the rectangular wave, and the level is  $500 \text{mV}_{p-p}$  (fosc = 1.45MHz, typ.)
- The higher local oscillation frequency (fosc) to be, the lower buff output level to be owing to the load capacity. So, in the case that it is connected to other circuits, take care of the input capacity of these circuits and stray capacity of wire.

#### 6. Tuning LED driver and stereo LED driver

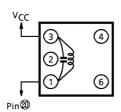
- The tuning LED driver and stereo LED driver don't have current limit resistance shown in the right figure. So, it is necessary to add the current limit resistance: R<sub>10</sub>, R<sub>11</sub>.
- Set up the values of R<sub>10</sub>, R<sub>11</sub> to keep the drive currents ID10, ID11 under 10mA.



#### 7.FM detection circuit

For the FM detection circuit, detection coil is able to use instead of ceramic discriminator. Recommended circuit and recommended coil are as follows. In this case, please take care that  $V_{in}$  (lim.) falls a little.





Tes	-	Co	Os		Tu	rns		Wire	REF
Freque	ency	(pF)	Q <sub>0</sub>	1–2	2–3	1–3	4–6	(mmφ)	IXEI
10.7M	ИHz	100	100	1	1	12	_	0.12 UEW	SUMIDA ELECTRIC CO., LTD 2153–4095–189 or equivalent

#### 8. FM / AM switch and forced monaural switch

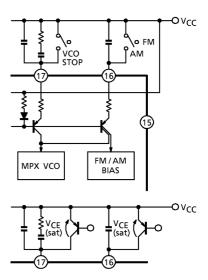
FM / AM switch over and stere / forced monaural switch over are done by internal PNP transistors ON / OFF which are connected to pin(16) and pin(17) respectively.

The threshold voltages of these PNP transistors are  $V_{th}$  =  $V_{CC}$ , and for switching, we recommend to use mechanical switch.

(Direct short to VCC line.)

In the case of the electrical switch over by transistor, set up VCE (saturation voltage between collector and emitter) 50mV or less, otherwise there are some cases that it does not become the AM mode and force monaural mode.

When these external switches are ON, the currents which flow into pin(16) and pin(17) are  $100\mu A$  and  $20\mu A$  respectively. (Typical value at VCC = 3V)



### **Maximum Ratings (Ta = 25°C)**

Characte	eristic	Symbol	Rating	Unit
Supply voltage		V <sub>CC</sub>	8	V
LED current		I <sub>LED</sub>	10	mA
LED voltage		V <sub>LED</sub>	8	V
Power dissipation	TA8132AN	PD (Note)	1200	mW
Power dissipation	TA8132AF	PD (Note)	400	IIIVV
Operating Temperatu	ire	T <sub>opr</sub>	-25~75	°C
Storage temperature		T <sub>stg</sub>	<b>−55~150</b>	°C

(Note): Derated above 25°C in the proportion of 9.6mW / °C for TA8132AN, TA2012N and of 3.2mW / °C for TA8132AF, TA2012F.



### **Electrical characteristics**

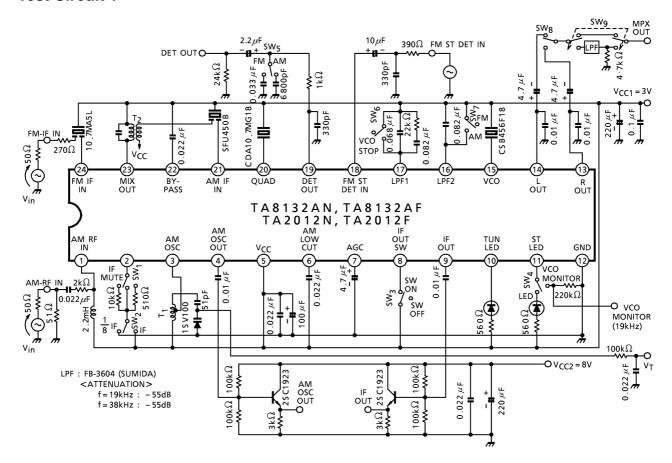
Unless Otherwise Specified, Ta = 25°C,  $V_{CC1}$  = 3V,  $SW_1 \rightarrow 10k\Omega$ ,  $SW_3 \rightarrow OFF$  FM IF: f = 10.7MHz,  $\Delta f$  = ±22.5kHz,  $f_m$  = 1kHz AM: f = 1MHz, MOD = 30%,  $f_m$  = 1kHz MPX:  $f_m$  = 1kHz

Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit		
Supply current		I <sub>CC</sub> (FM)	1	FM mode, V <sub>in</sub> = 0	_	11.0	14.0	- mA		
Suppi	y current		I <sub>CC</sub> (AM)	1	AM mode, V <sub>in</sub> = 0	_	10.5	13.5	mA	
	Input limiting voltage	9	V <sub>in (lim.)</sub>	1	-3dB limiting point	41	46	51	dBµV EMF	
	Recovered o	output	V <sub>OD</sub>	1	V <sub>in</sub> = 80dBμV EMF	50	75	100	mV <sub>rms</sub>	
	Signal to no ratio	ise	S/N	1	V <sub>in</sub> = 80dBμV EMF	_	65	_	dB	
	Total harmo	nic	THD	1	V <sub>in</sub> = 80dBμV EMF	_	0.2	_	%	
	AM rejection	n ratio	AMR	1	V <sub>in</sub> = 80dBμV EMF	_	38	_	dB	
	LED on sensitivity		$V_{L}$	1	I <sub>L</sub> = 1mA	48	53	58	dBµV EMF	
FM	IF count output frequency	IF	f <sub>IF</sub> (FM)	1	$V_{in}$ = 80dB $\mu$ V EMF, SW $_2$ $\rightarrow$ V <sub>CC</sub> , SW $_3$ $\rightarrow$ ON	_	10.7	_	MHz	
IF		1 / 8 IF	f <sub>1 / 8 IF</sub> (FM)	1	$V_{in}$ = 80dB $\mu$ V EMF, SW $_2$ $\rightarrow$ GND, SW $_3$ $\rightarrow$ ON	1.3374	1.3375	1.3376	IVIMZ	
	IF count output	IF	V <sub>IF</sub> (FM)	1	$V_{in}$ = 61dB $\mu$ V EMF, SW <sub>2</sub> $\rightarrow$ V <sub>CC</sub> , SW <sub>3</sub> $\rightarrow$ ON	350	500	_	m\/	
	voltage	1 / 8 IF	V <sub>1 / 8 IF</sub> (FM)	1	$V_{in}$ = 61dB $\mu$ V EMF, SW $_2$ $\rightarrow$ GND, SW $_3$ $\rightarrow$ ON	350	500	_	mV <sub>p-p</sub>	
					$SW_1 \rightarrow 0$ , $SW_2 \rightarrow GND$ , $SW_3 \rightarrow ON$	_	76	_		
	IF count out	put	 	1	$SW_1 \rightarrow 510\Omega$ , $SW_2 \rightarrow GND$ , $SW_3 \rightarrow ON$	_	68	_	dΒμV	
	sensitivity		IF <sub>sens.</sub> (FM)	'	$SW_1 \rightarrow 0$ , $SW_2 \rightarrow V_{CC}$ , $SW_3 \rightarrow ON$	_	77	_	EMF	
					$SW_1 \rightarrow 510\Omega$ , $SW_2 \rightarrow$ , $V_{CC}$ , $SW_3 \rightarrow ON$	_	69	_		

	Characteristic	Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit	
	Gain	G <sub>V</sub>	1	V <sub>in</sub> = 26dBμV EMF	28	57	85		
	Recovered output voltage	V <sub>OD</sub>	1	V <sub>in</sub> = 60dBμV EMF	50	75	100	mV <sub>rms</sub>	
	Signal to noise ratio	S/N	1	V <sub>in</sub> = 60dBμV EMF	_	41	_	dB	
	Total harmonic distortion	THD	1	V <sub>in</sub> = 60dBμV EMF	_	1.0	_	%	
	LED on sensitivity	VL	1	I <sub>L</sub> = 1mA	21	26	31	dBµV EMF	
	Local OSC buff. output voltage	V <sub>OSC</sub> (AM)	1	f <sub>OSC</sub> = 1.45MHz	$f_{OSC} = 1.45MHz$ 350 500		_	m\/	
AM			2	f <sub>OSC</sub> = 27MHz	_	500	_	mV <sub>p-p</sub>	
	IF count output voltage	V <sub>IF</sub> (AM)	1	V <sub>in</sub> = 39dBμV EMF, SW <sub>3</sub> →ON	350	500	_	$mV_{p-p}$	
				$SW_1 \rightarrow 0$ , $SW_2 \rightarrow GND$ , $SW_3 \rightarrow ON$	_	49	_		
	IF count output	le.	1	$SW_1 \rightarrow 510\Omega$ , $SW_2 \rightarrow GND$ , $SW_3 \rightarrow ON$	_	42	_	dΒμV EMF	
	sensitivity	IF <sub>sens. (AM)</sub>	'	$SW_1 \rightarrow 0$ , $SW_2 \rightarrow V_{CC}$ , $SW_3 \rightarrow 0$	_	49	_		
				$SW_1 \rightarrow 510\Omega$ , $SW_2 \rightarrow$ , $V_{CC}$ , $SW_3 \rightarrow ON$	_	42	_		
Din/10	9) output resistance	R <sub>19</sub>	1	FM mode	_	0.6	_	kO.	
1.111(13	o) output resistance	N19	'	AM mode	_	12		- kΩ	

	Characteristic		Symbol	Test Cir– cuit	Test Cond	ition	Min.	Тур.	Max.	Unit
	Input resist	ance	R <sub>IN</sub>	1	_		_	25	_	kΩ
	Output resi	stance	R <sub>OUT</sub>	1	_		_	5	_	K77
	Max. composignal input		V <sub>in MAX</sub> (stereo)	1	L + R = 90%, P = 10% THD = 3%, SW <sub>9</sub> →LPF	: ON	_	350	_	mV <sub>rms</sub>
					L + R = 135mV <sub>rms</sub>	f <sub>m</sub> = 100kHz	_	42	_	
	Separation		Sep	_	$P = 15 \text{mV}_{\text{rms}}$	f <sub>m</sub> = 1kHz	35	42	_	dB
					SW <sub>9</sub> →LPF: ON	f <sub>m</sub> = 10kHz	_	42	_	
	Total	Monaural	THD (monaural)		V <sub>in</sub> = 150 mV <sub>rms</sub> (mono	0)	_	0.2	_	
MPX	harmonic distortion	Stereo	THD (stereo)	1	L + R = 135mV <sub>rms</sub> , P = 15mV <sub>rms</sub> SW <sub>9</sub> →LPF: ON		_	0.2	_	%
	Voltage gai	n	G <sub>V</sub> (MPX)	1	V <sub>in</sub> = 150mV <sub>rms</sub> (mono	)	-5	-3	-1	dB
	Channel ba	lance	C.B.	1	V <sub>in</sub> = 150mV <sub>rms</sub> (mono	))	-2	0	2	dB
	Stereo LED	ON	V <sub>L</sub> (ON)	1	Pilot input		_	8	15	m\/
	sensitivity	OFF	V <sub>L</sub> (OFF)	] '	Pilot iliput		2	6	_	mV <sub>rms</sub>
-	Stereo LED	hysteresis	V <sub>H</sub>	1	To LED turn off from LED turn on		_	2	_	mV <sub>rms</sub>
	Capture rar	nge	C.R.	1	P = 15mV <sub>rms</sub>		_	±1.3	_	%
	Signal to no	oise ratio	S/N	1	V <sub>in</sub> = 150mV <sub>rms</sub> (mono	)	_	78	_	dB

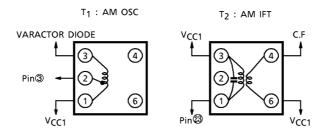
### **Test Circuit 1**



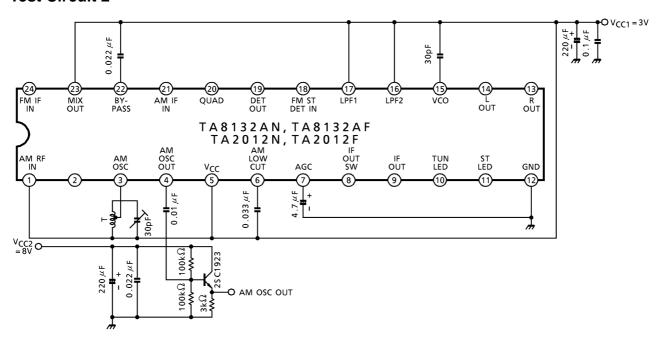
### Coil Data (test circuit 1)

Coil No.	f	L (µH)	C <sub>o</sub> (pF)	Qo	Turn				Wire	DED (Cail Na.)
					1–2	2–3	1–3	4–6	(mm)	RED. (Coil No.)
T <sub>1</sub> AM OSC	796kHz	288	_	115	13	73	_	_	0.08 UEW	4147-1356-038 (S)
T <sub>2</sub> AM IFT	455KHz	_	180	120	-	_	180	15	0.06 UEW	2150-2162-165 (S)

(S): SUMIDA ELECTRIC Co., Ltd.



### **Test Circuit 2**

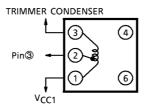


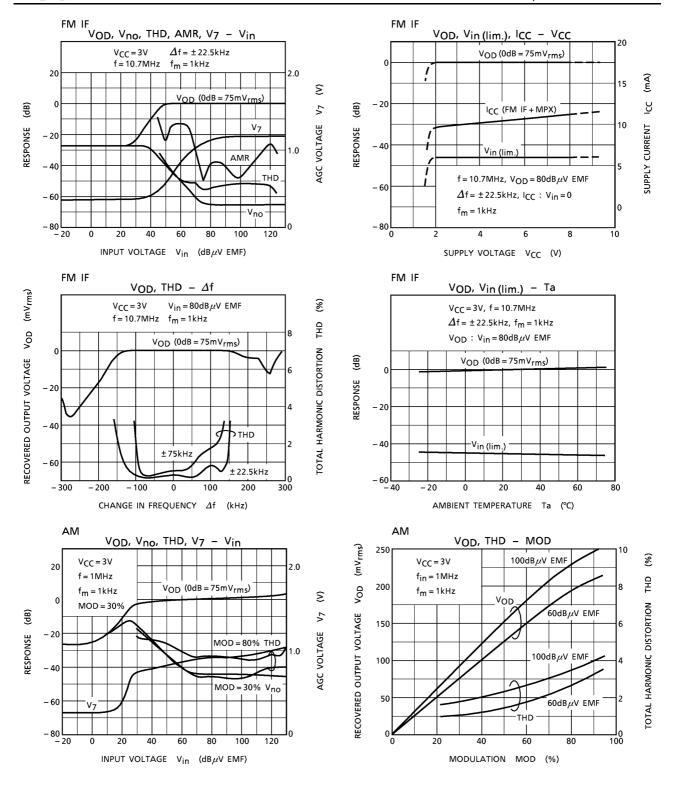
### Coil Data (test circuit 2)

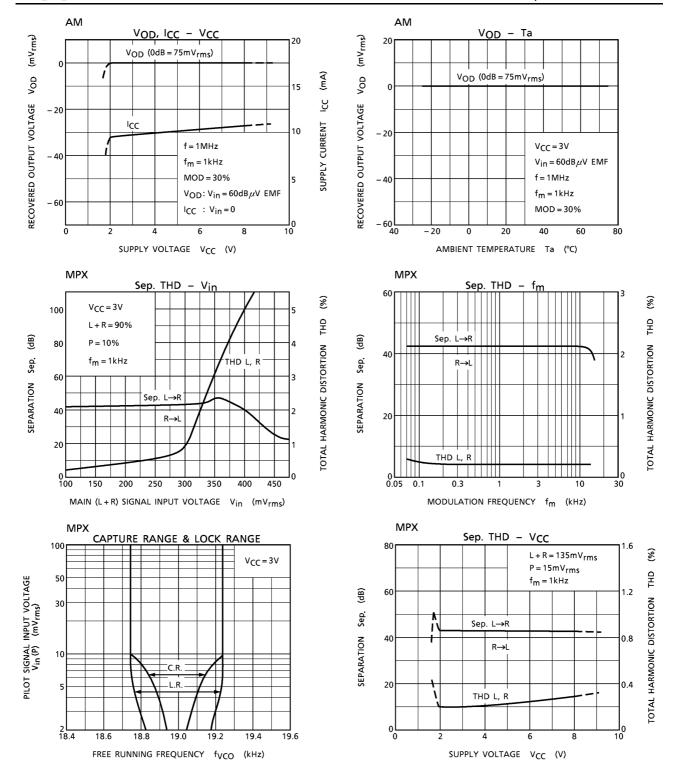
	Coil No.	f	L	Co		Turn				Wire	REF. (Coil No.)
Coll No.	ı	(µH)	(pF)	Q <sub>o</sub>	1–2	2–3	1–3	4–6	(mm)	KLI . (Coll No.)	
	T AM OSC	7.96MHz	1.4	_	84	1	6	7	_	0.08 UEW	(T) 7PL-1344Y

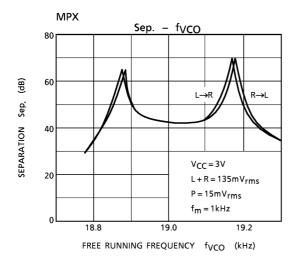
(T): TOKO Co., Ltd.

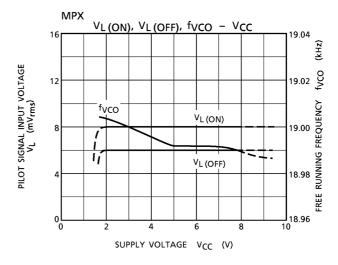
T: AM OSC







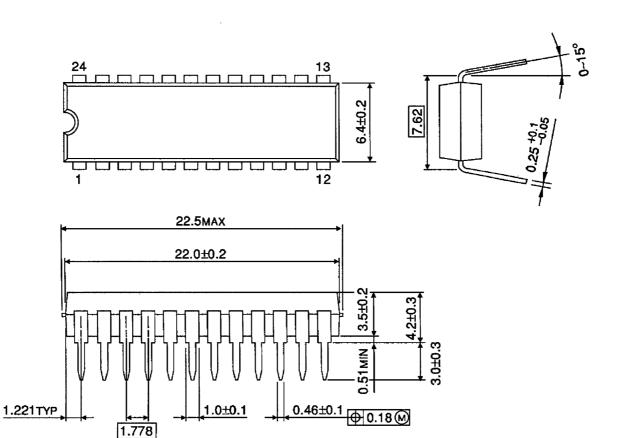




Unit: mm

# **Package Dimensions**

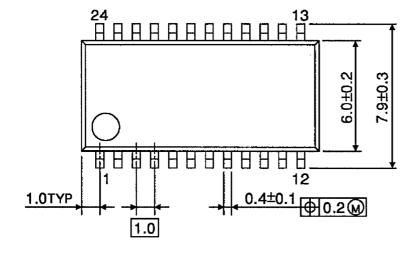
SDIP24-P-300-1.78

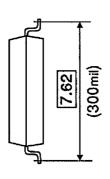


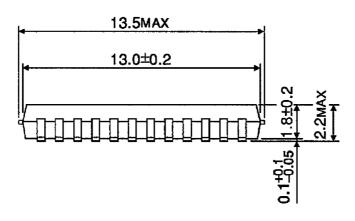
Weight: 1.2g (typ.)

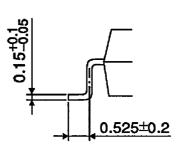
## **Package Dimensions**

SSOP24-P-300-1.00 Unit: mm









Weight: 0.31g (typ.)

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000707EBA

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